Photo Semiconductor Device - Page 1 of 1



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	nclosure Material:
	Aetal and glass
	Overall Length:
C	0.146 inches
٦	erminal Length:
1	.070 inches
C	Overall Diameter:
C	0.210 inches
F	Function For Which Designed:
F	Photodiode
I	nternal Configuration:
J	unction contact
M	Nounting Method:
٦	- Ferminal
S	Semiconductor Material:
S	Silicon
M	Aximum Operating Tempurature Per Measurement Point:
1	25.0 degrees celsius ambient air
S	Special Features:
J	unction pattern arrangement: pin
٦	erminal Type And Quantity:
2	2 uninsulated wire lead
S	Shelf Life:
١	l/a
ι	Jnit Of Measure:
-	-
[	Demilitarization:
١	'es - demil/mli
F	iig:
A	x110a0